Synthesis and Structure of the Scandium-Rich Indides $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$

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ABSTRACT: The ternary indides Sc_5 Ni_2 In_4 and Sc_5 *Rh2 In4 were synthesized by arc-melting of the elements and subsequent annealing. A structural investigation by X-ray powder and single crystal diffraction revealed: Lu5 Ni2 In4 type, Pbam, a* = *1716.3(2), b* = *755.1(1), c* = *335.22(5) pm, wR2* = *0.0721, 844 F2 values for Sc₅* Ni_2 In_4 , and $a = 1754.3(3)$, $b = 765.0(1)$, $c =$ *332.97(6) pm, wR2* = *0.0363, 1107 F2 values for Sc5 Rh2 In4 with 36 variables per refinement. Both structures can be described as intergrowths of dis*torted AlB₂- and CsCl-related slabs, where the transi*tion metal (T) atoms have a trigonal prismatic and the indium atoms a distorted square prismatic coordination. The shortest interatomic distances occur for Sc T and T In. The crystal chemistry and chemical bonding in these intermetallics are briefly discussed.* ^C 2005 Wiley Periodicals, Inc. Heteroatom Chem 16:364–368, 2005; Published online in Wiley InterScience (www.interscience.wiley.com). DOI 10.1002/hc.20106

INTRODUCTION

Many structures of complex intermetallic compounds in the ternary systems $R-T-X$ ($R = Ti$, Zr, Hf, rare earth or actinoid metal; $T =$ late transition metal; $X =$ element of the 3rd, 4th, or 5th main group) can be described as intergrowths of slightly distorted slabs that are related to simple binary or ternary structure types such as AlB_2 , Cu₃Au, CaCu₅, CsCl, $BaAl₄$, NaCl, and others $[1-6]$.

The various intergrowths for the rare earthtransitions metal-indides have recently been reviewed [7]. Several of these indides crystallize with distorted CsCl- and AlB_2 - related slabs in different tessellation. Prominent examples are indides with the tetragonal $Mo₂FeB₂[8, 9, and reference, therein],$ the orthorhombic Mn_2AlB , [10], or the orthorhombic Lu₅Ni₂In₄- type structure [11]. More than 100 indides crystallize with these three structure types. With the rare earth elements, the indides $RE_5Ni_2In_4$ $(RE = Ho, Er, Tm, Lu)$ have been reported [11]. The structure type was determined for $Lu_5Ni_2In_4$, space group *Pbam*, and $Z = 2$.

Due to the lanthanoid contraction, the metallic and the covalent radii of hafnium and zirconium are almost identical [12] although hafnium has about twice the atomic mass. Consequently, zirconium and hafnium have very similar chemical properties and in the field of intermetallics they often form isotypic compounds. During our recent phase analytical investigations in the $(Zr, Hf) - T - In$ systems, we obtained the indides $Zr_5Rh_2In_4$ and $Hf_5Rh_2In_4$ [13] which are isotypic with the $RE_5Ni_2In_4$ compounds. $Zr_5Ir_2In_4$ [14] also crystallizes with a pronounced $Lu_5Ni_2In_4$ -type subcell; however, weak superstructure reflections require doubling of the subcell *c*-axis. The difference in size between rhodium and iridium

Dedicated to Professor Dr. Alfred Schmidpeter on the occasion of his 75th birthday.

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is most likely responsible for the small structural distortions.

The size of zirconium and hafnium is similar to that of scandium [12], the smallest of the rare earth metals. We have now investigated such scandium compounds and found the new $Lu_5Ni_2In_4$ type indides $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$. The synthesis and crystal chemistry of these intermetallics are reported herein.

RESULTS AND DISCUSSION

The structures of $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$ have been refined on the basis of single crystal X-ray data. They crystallize with the orthorhombic $Lu_5Ni_2In_4$ type. As an example, we present a projection of the $Sc_5Rh_2In_4$ structure onto the *xy* plane in Fig. 1. Since the structure refinement revealed slightly better values for $Sc_5Rh_2In_4$, in the following discussion we focus on the rhodium compound. From a purely geometrical point of view, the structure can be considered as an intergrowth of distorted CsCl- and AlB_2 - related slabs. All indium atoms have a strongly distorted square prismatic coordination, while the smaller rhodium atoms are located in distorted trigonal prisms.

The shortest distances in the $Sc_5Rh_2In_4$ structure occur for Sc-Rh. The latter range from 263 to 279 pm, close to the sum of the covalent radii of 269 pm [12]. Similar trigonal [RhSc₆] prisms occur in the indide $Sc_3Rh_{1.594}In_4$ with a new ZrNiAl super-

FIGURE 1 Projection of the Sc₅Rh₂In₄ structure onto the xy plane. All atoms lie on mirror planes at $z = 1/2$ (thin lines) and *z* = 1 (thick lines). Scandium, rhodium, and indium atoms are drawn as medium gray, filled, and open circles, respectively. Atom designations are indicated. The distorted trigonal prismatic rhodium coordination ($AIB₂$ slab) and the distorted square prismatic indium coordination (CsCl slab) are emphasized. For clarity, only Rh–In bonds are drawn in the $[Rh_2]n_4]$ network at $z = 1/2$.

structure [15]. Here, the $Sc-Rh$ distances are 272 and 273 pm. All of these Sc-Rh distances are comparable to those in CsCl-type ScRh (278 pm) [16] and Cu₃Au-type ScRh₃ (276 pm) [17]. We can thus assume strong Sc-Rh bonding in $Sc_5Rh_2In_4$.

The rhodium and indium atoms at $z = 1/2$ build up two-dimensional $[Rh_2In_4]$ networks as emphasized in Fig. 1. Each rhodium atom has three indium neighbors in an almost trigonal-planar coordination. Two indium neighbors are at Rh-In distances of 285 and 289 pm, while the third indium atom is at 311 pm. The shorter Rh-In distances are only slightly longer than the sum of the covalent radii of 275 pm. The third contact can only be considered as weak as indicated by dotted lines in the figure. Within the network, each indium atom has three close indium neighbors at In-In distances varying from 315 to 333 pm, similar to elemental, tetragonal body-centered indium [18], where each indium atom has four nearest indium neighbors at 325 pm and eight further neighbors at 338 pm. The two-dimensional $[Rh_2In_4]$ networks are thus governed by strong Rh-In and In-In bonding as well. While the Rh-In bonding exclusively occurs within the $[Rh_2In_4]$ layers, the In-In distances at 333 pm (the unit cell *c* axis) condense the layers in the third direction.

Finally we need to comment on the Sc-Sc contacts in this metal-rich indide. Each of the three crystallographically different scandium atoms has between two and four scandium neighbors at relatively short Sc—Sc distances between 323 and 333 pm. The latter corresponds to the unit cell *c* axis. Additionally, a variety of longer Sc-Sc distances between 353 and 396 pm occurs. The shorter Sc-Sc distances are similar to the average Sc-Sc distance of 328 pm in *hcp* scandium $[18]$. Thus we observe significant Sc $-Sc$ bonding within the scandium layers at $z = 0$ and also between these layers.

For different drawings of the structure and for a more detailed discussion of the crystal chemistry and chemical bonding of the $Lu_5Ni_2In_4$ -type intermetallics, we refer to previous manuscripts [11,13,14].

EXPERIMENTAL

Synthesis

Starting materials for the preparation of $Sc₅Ni₂In₄$ and $Sc_5Rh_2In_4$ were scandium ingots (Kelpin), nickel wire (Ø 0.38 mm, Johnson-Matthey), rhodium powder (Degussa, ca. 200 mesh), and indium teardrops (Johnson-Matthey), all with stated purities better than 99.9%). In a first step, pieces of the scandium

ingot were arc melted [19] to small buttons under an argon atmosphere of ca. 600 mbar. The argon was purified before over molecular sieves, silica gel, and titanium sponge (900 K). This premelting procedure strongly reduces shattering during the subsequent reactions. The scandium button, pieces of the nickel wire (a cold-pressed pellet of rhodium), and pieces of the indium tear drops were weighed in the ideal 5:2:4 atomic ratios and arc melted. The resulting buttons were remelted three times in order to ensure homogeneity. The total weight losses after the arc-melting procedures were always smaller than 0.5%.

 $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$ were obtained only in polycrystalline form by arc melting. For crystal growth, pieces of the arc-melted samples were sealed in small evacuated tantalum tubes [19]. The latter have been enclosed in evacuated silica ampoules for oxidation protection and first rapidly heated at 1320 K for 7 h, cooled at a rate of 3 K/h to 1020 K, then at a rate of 4 K/h to 770 K, and finally quenched by switching off the furnace. Both annealing procedures resulted in loose agglomerates of crystals nicely separated from the polycrystalline material. The samples could quantitatively be separated from the tantalum tubes. No reactions with the crucible material were observed. $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$ are stable in moist air over months. Fine-grained powders are dark gray; single crystals exhibit metallic luster.

EDX Analyses

The single crystals investigated on the diffractometer were analyzed with a Leica 420 I scanning electron microscope using Sc, Ni, Rh, and InAs as standards. No metallic impurity elements were detected. Analyses of the single crystals revealed the compositions 45 ± 2 at.% Sc : 16 ± 2 at.% Ni : 39 ± 2 at.% In, and 45 ± 2 at.% Sc : 18 ± 2 at.% Rh : 37 ± 2 at.% In, close to the ideal composition of 45.5 : 18.2 : 36.3. The relatively high standard deviations account for the different measurements and for the irregular surface of the crystals.

X-ray Investigations

Both samples were characterized through Guinier powder patterns after the arc-melting procedure and after the annealing program. The Guinier camera was equipped with an image plate system (Fujifilm BAS-1800). Cu K α_1 radiation was used and α -quartz (*a* = 491.30 pm, *c* = 540.46 pm) was taken as an internal standard. The lattice parameters (Table 1) were obtained from least-squares fits of the powder data. The correct indexing of the patterns was ensured through intensity calculations [20] taking the atomic positions from the structure refinements. The lattice parameters determined from the powders and the single crystals agreed well.

The lath-shaped silvery single crystals of $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$ were strongly agglomerated. As an example we present such an agglomerate of $Sc_5Ni_2In_4$ in Fig. 2. They were carefully separated by mechanical fragmentation and mounted on quartz fibers. They were examined by Laue photographs on a Buerger precession camera (Mo radiation) equipped with an image plate system (Fujifilm BAS-1800) in order to establish suitability for intensity data collection. Single crystal intensity data were collected at room temperature by use of a Stoe IPDS-II diffractometer (oscillation mode) with graphite monochromatized Mo K*α* radiation (71.073 pm). Numerical absorption corrections were applied to the data. All relevant crystallographic data and experimental details for both data collections are listed in Table 2.

Structure Refinements

The isotypism of $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$ with $Zr_5Rh_2In_4$ [13] was already evident from the X-ray powder data. The systematic extinctions were compatible with the centrosymmetric space group *Pbam*, in agreement with the previous investigations [11,13]. During the integration procedure, the data set was carefully analyzed with respect to superstructure reflections. There was no hint for doubling of the subcell *c* axis as in $Zr_5Ir_2In_4$ [14]. The atomic parameters of $Zr_5Rh_2In_4$ were used as starting values, and both structures were refined using SHELXL-97 (full-matrix least-squares on F_o^2) [21] with anisotropic atomic displacement parameters for all atoms. In a saeparate series of least-squares cycles, we refined the occupancy parameters to check for

FIGURE 2 Scanning electron micrograph of agglomerated Sc₅Ni₂In₄ crystals.

Compound	a (pm)	b (pm)	c (pm)	V (nm ³)	Ref.
$Ho_5Ni_2In_4$	1776.8(5)	788.8(3)	356.8(2)	0.5001	$[11]$
Er_5 Ni ₂ In ₄	1772.2(8)	786.6(4)	355.8(3)	0.4960	$[11]$
$Tm_5Ni_2In_4$	1765.3(6)	784.3(3)	354.2(3)	0.4904	[11]
Lu ₅ Ni ₂ In ₄	1756.8(5)	779.8(2)	352.2(1)	0.4825	[11]
Sc_5 Ni ₂ In ₄	1716.3(2)	755.1(1)	335.22(5)	0.4345	This work
$Sc5Rh2ln4$	1754.3(3)	765.0(1)	332.97(6)	0.4469	This work
$Zr_5Rh_2In_4$	1739.8(2)	758.3(1)	337.42(5)	0.4452	[13]
$Hf_5Rh_2In_4$	1732.1(3)	757.5(2)	333.36(7)	0.4374	$[13]$
Zr_5 Ir ₂ In ₄	1739.5(6)	766.3(2)	338.9(2)	0.4518	$[14]$

TABLE 1 Lattice Parameters of Orthorhombic Indides with Lu5Ni2In4 Type Structure, Space Group *Pbam*. For Zr5Ir2In4 only the Subcell Data Are Listed [14]

TABLE 2 Crystal Data and Structure Refinement for Sc₅Ni₂In₄ and Sc₅Rh₂In₄ (Space Group *Pbam*, Z = 2, oP22)

Empirical formula Molar mass Unit cell dimensions	$Sc_5Ni_2In_4$ 801.50 g/mol Table 1	$Sc_5Rh_2In_4$ 889.90 g/mol Table 1
Calculated density	6.13 $g/cm3$	6.61 g/cm^{3}
Crystal size Transm. ratio (max/min)	$40 \times 40 \times 140 \ \mu m^3$ 2.59	$10 \times 20 \times 120 \ \mu m^3$ 1.82
Absorption coefficient F(000)	18.2 mm ^{-1} 714	17.2 mm ^{-1} 782
Detector distance	80 mm	60 mm
Exposure time	14 min	20 min
ω range; increment	$0 - 180^{\circ}, 1.0^{\circ}$	$0 - 180^{\circ}$, 1.0 $^{\circ}$
Integr. parameters A, B, EMS	14.5; 4.5; 0.012	14.5; 4.5; 0.014
θ range	2° to 32°	3° to 35°
Range in hkl	$\pm 25, \pm 10, \pm 4$	\pm 28, \pm 12, \pm 5
Total no. reflections	4965	6324
Independent reflections	844 ($R_{\text{int}} = 0.0417$)	1107 ($R_{\text{int}} = 0.0273$)
Reflections with $1>2\sigma(1)$	800 ($R_{\text{sigma}} = 0.0211$)	1017 ($R_{\text{sigma}} = 0.0149$)
Data/parameters	844 / 36	1107 / 36
Goodness-of-fit on F^2	1.141	1.148
Final R indices $[1>2\sigma(1)]$	$R_1 = 0.0281$ $wR_2 = 0.0711$	$R_1 = 0.0186$ $wR_2 = 0.0352$
<i>R</i> indices (all data)	$R_1 = 0.0299$ $wR_2 = 0.0721$	$R_1 = 0.0230$ $wR_2 = 0.0363$
Extinction coefficient	0.006(1)	0.0028(4)
Largest diff. peak and hole	1.13 and -1.11 e/ \AA^3	1.05 and -1.18 e/ \AA^3

 U_{eq} is defined as one third of the trace of the orthogonalized U_{ij} tensor.

deviations from the ideal composition, especially since rhodium and indium differ only by four electrons. Since all sites were fully occupied within two standard deviations, the ideal occupancies were assumed again in the final cycles. Final difference Fourier syntheses revealed no significant residual peaks (Table 2). The positional parameters and interatomic distances are listed in Tables 3 and 4. Further details on the structure refinements may be obtained from: Fachinformationszentrum Karlsruhe,

TABLE 4 Interatomic Distances (pm), Calculated with the Lattice Parameters Taken from X-ray Powder Data of $Sc_5Ni_2In_4$ and $Sc_5Rh_2In_4$

$Sc_5Ni_2In_4$				$Sc_5Rh_2In_4$			
Sc1:	4	In1	303.8	$Sc1$:	4	In1	305.3
	4	ln2	314.6		4	ln2	315.5
	2	Sc ₃	319.9		2	Sc ₃	322.9
		Sc1	335.2			Sc1	333.0
Sc ₂ :		Ni	274.3	Sc2:		Rh	276.9
		Ni	276.7		$\begin{array}{c}\n2 \\ 2 \\ 2\n\end{array}$	Rh	278.5
		ln2	306.2			ln2	312.4
		ln 1	312.9		$\begin{array}{c}\n2 \\ 2 \\ 2\n\end{array}$	ln 1	317.8
	2222222	ln2	319.2			ln2	323.3
		Sc ₂	335.2		\overline{c}	Sc ₂	333.0
	$\mathbf{1}$	Sc ₃	346.6		$\mathbf{1}$	Sc ₃	355.8
	$\mathbf{1}$	Sc ₃	364.0		1	Sc3	370.7
	\overline{c}	Sc ₂	390.9		\overline{c}	Sc ₂	396.2
Sc3:	222 22	Ni	260.0	Sc3:	2 2 2 2	Rh	263.3
		In1	299.1			In1	302.8
		ln2	306.2			ln2	309.0
		In1	317.8			ln 1	319.9
	$\mathbf{1}$	Sc1	319.9		$\mathbf{1}$	Sc1	322.9
	\overline{c}	Sc ₃	335.2		\overline{c}	Sc ₃	333.0
	$\mathbf{1}$	Sc ₃	348.0		$\mathbf{1}$	Sc ₃	353.0
	$\mathbf{1}$	Sc ₂	346.6		$\mathbf{1}$	Sc ₂	355.8
	$\mathbf{1}$	Sc ₂	364.0		$\mathbf{1}$	Sc ₂	370.7
Ni:	$\overline{\mathbf{c}}$ \overline{c}	Sc3	260.0	Rh:	$\overline{\mathbf{c}}$	Sc ₃	263.3
	\overline{c}	Sc ₂	274.3		$\overline{\mathbf{c}}$ \overline{c}	Sc ₂	276.9
	$\mathbf{1}$	Sc ₂ ln2	276.7 275.6		$\mathbf{1}$	Sc ₂ ln2	278.5 285.5
	1	ln 1	283.4		1	ln ₁	288.9
	1	ln2	303.8		$\mathbf{1}$	ln2	310.9
$ln1$:	$\mathbf{1}$	Ni	283.4	$ln1$:	$\mathbf{1}$	Rh	288.9
	\overline{c}	Sc ₃	299.1			Sc ₃	302.8
	\overline{c}	Sc1	303.8		$\frac{2}{2}$	Sc1	305.3
	$\mathbf{1}$	ln2	314.5		$\mathbf{1}$	ln2	315.1
	\overline{c}	Sc ₂	312.9		\overline{c}	Sc ₂	317.8
		Sc ₃	317.8			Sc ₃	319.9
	$\frac{2}{2}$	ln 1	335.2		$\frac{2}{2}$	ln 1	333.0
	$\mathbf{1}$	ln ₁	383.9		$\mathbf{1}$	ln 1	390.7
$ln2$:	1	Ni	275.6	$ln2$:	$\mathbf{1}$	Rh	285.5
	$\mathbf{1}$	Ni	303.8		\overline{c}	Sc ₃	309.0
	$\overline{\mathbf{c}}$	Sc ₂	306.2		$\mathbf{1}$	Rh	310.9
	\overline{c}	Sc ₃	306.2		$\overline{\mathbf{c}}$	Sc ₂	312.4
	$\mathbf{1}$	ln 1	314.5		$\mathbf{1}$	ln 1	315.1
	\overline{c}	Sc1	314.6		\overline{c}	Sc1	315.5
	$\frac{2}{2}$	Sc ₂	319.2		$\frac{2}{2}$	Sc ₂	323.3
		ln2	335.2			ln2	333.0

All distances within the first coordination spheres are listed. Standard deviations are all equal or less than 0.2 pm.

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